3Q Hi-Com Triac 4 October 2012

Product data sheet

Product profile 1.

1.1 General description

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. This "series C" triac will commutate the full RMS current at the maximum rated junction temperature without the aid of a snubber.

1.2 Features and benefits

- 3Q technology for improved noise immunity
- High commutation capability with maximum false trigger immunity
- High voltage capability •
- Less sensitive gate for high noise immunity •
- Planar passivated for voltage ruggedness and reliability •
- Triggering in three quadrants only •
- Very high immunity to false turn-on by dV/dt

1.3 Applications

- Electronic thermostats (heating and cooling) •
- High power motor controls e.g. washing machines and vacuum cleaners
- Rectifier-fed DC inductive loads e.g. DC motors and solenoids •

1.4 Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	800	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{ Fig. 4; Fig. 5}$	-	-	100	A
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{mb} \le 100$ °C; Fig. 1; Fig. 2; Fig. 3	-	-	12	A
Static chara	octeristics					
I _{GT}	gate trigger current	V_D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA





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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _i = 25 °C; <u>Fig. 7</u>	2	-	35	mA

2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	T2
2	T2	main terminal 2		sym051
3	G	gate		
mb	Τ2	mounting base; main terminal 2		
			TO-220AB (SOT78)	

3. Ordering information

Table 3.Ordering information

Type number	Package					
	Name	Description	Version			
BTA312-800C	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			
BTA312-800C/DG	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78			

4. Limiting values

Table 4.Limiting values

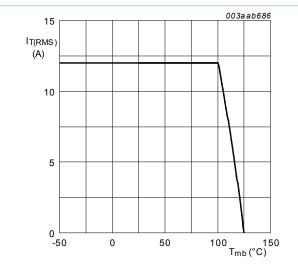
In accordance with the Absolute Maximum Rating System (IEC 60134).

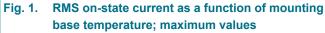
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 100 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	100	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	110	A

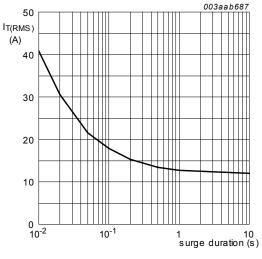
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Symbol	Parameter	Conditions	I	Min	Мах	Unit
l ² t	I ² t for fusing	t _p = 10 ms; SIN		-	50	A ² s
dI _T /dt	rate of rise of on-state current	$I_T = 20 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A/}\mu\text{s}$		-	100	A/µs
I _{GM}	peak gate current			-	2	А
P _{GM}	peak gate power			-	5	W
P _{G(AV)}	average gate power	over any 20 ms period		-	0.5	W
T _{stg}	storage temperature			-40	150	°C
Tj	junction temperature			-	125	°C

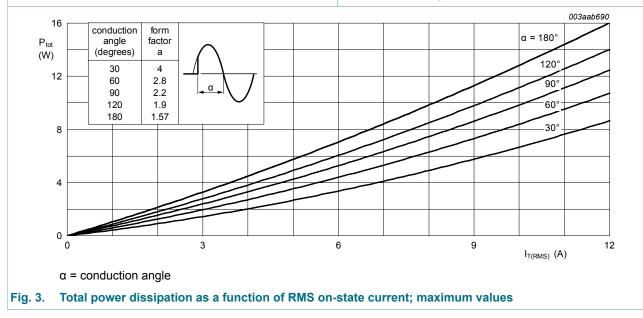






f = 50 Hz; T_{mb} = 100 °C

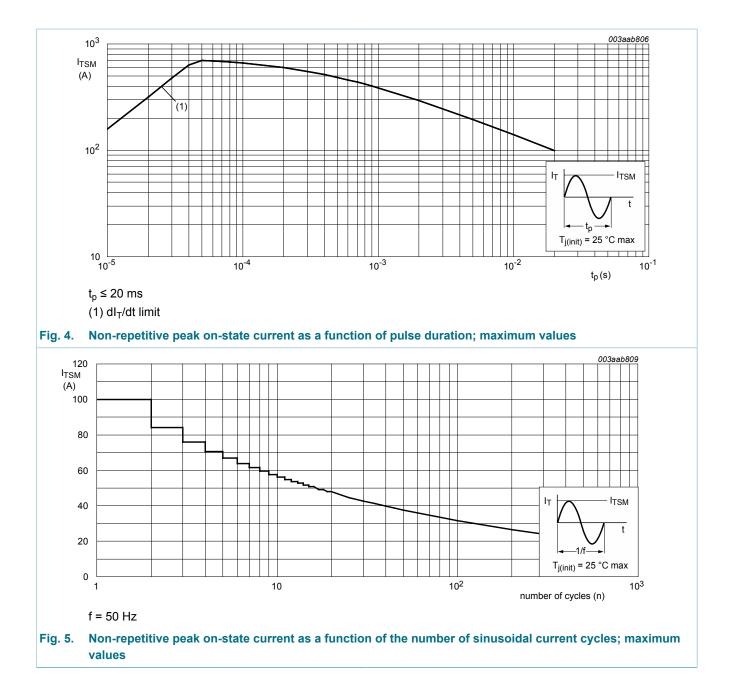
Fig. 2. RMS on-state current as a function of surge duration; maximum values



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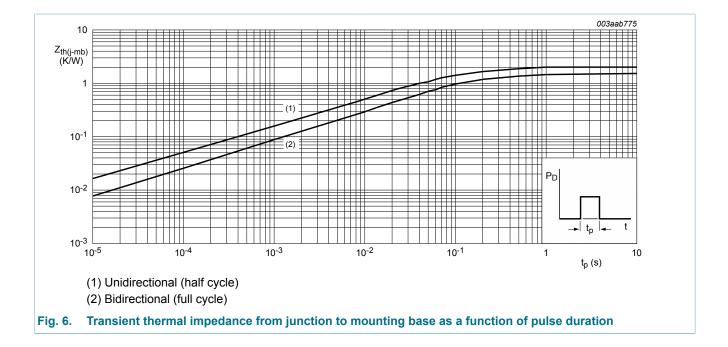


5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	thermal resistance	full cycle; Fig. 6	-	-	1.5	K/W
	from junction to mounting base	half cycle; <u>Fig. 6</u>	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

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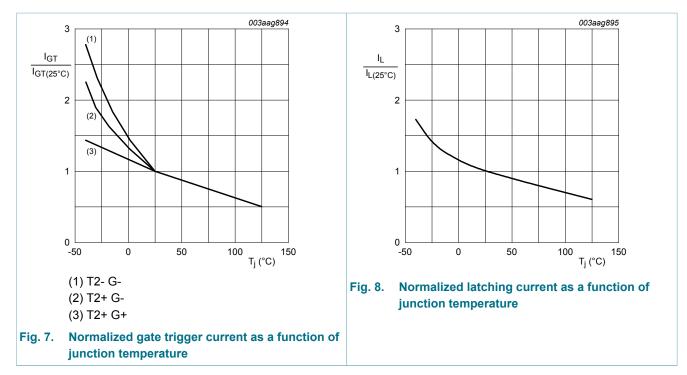
6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static char	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	2	-	35	mA
ΙL	latching current	V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
		V_D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	35	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11	0.25	0.4	-	V
		V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.8	1.5	V
I _D	off-state current	V _D = 800 V; T _i = 125 °C	-	0.1	0.5	mA

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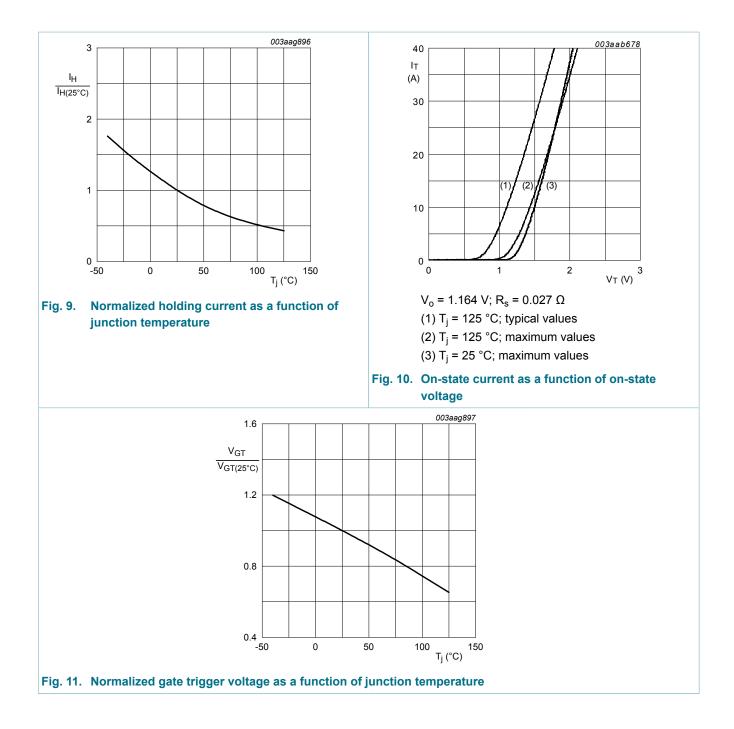
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Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Dynamic ch	Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit		500	-	-	V/µs	
dl _{com} /dt	rate of change of commutating current	$\label{eq:VD} \begin{array}{l} V_{D} = 400 \; V; \; T_{j} = 125 \;^{\circ}C; \; I_{T(RMS)} = 12 \; A; \\ dV_{com}/dt = 20 \; V/\mus; \; (snubberless \\ condition); \; gate \; open \; circuit \end{array}$		20	-	-	A/ms	



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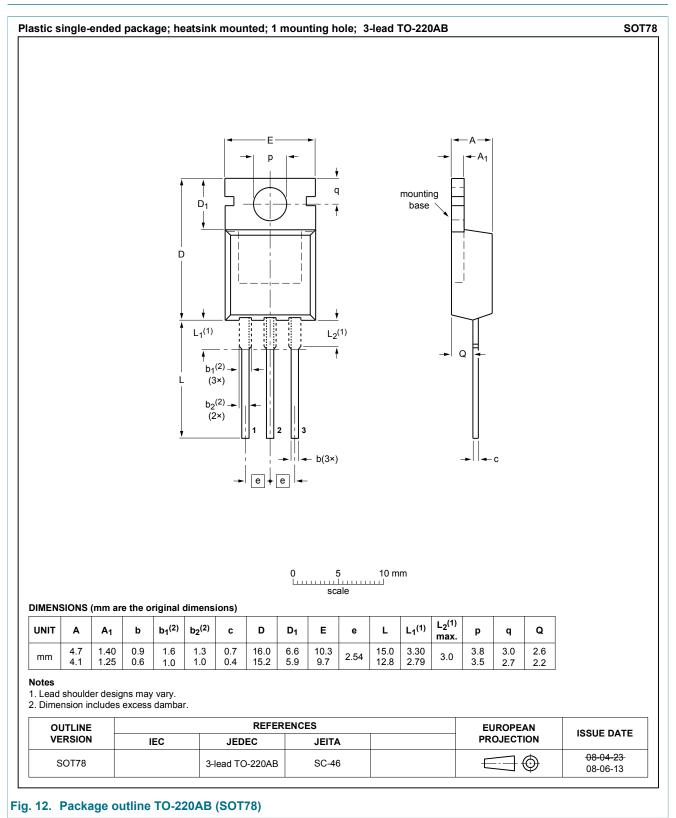
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7. Package outline



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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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